

## WG3: Discussions

Ioana Pintilie  
Jörn Schwandt

*1<sup>st</sup> DRD3 Workshop  
Working group 3 (WG3) Session  
19<sup>th</sup> June 2024*

<b>WG3 research goals &lt;2027</b>	
	<b>Description</b>
<b>RG 3.1</b>	Start of building up data sets on radiation-induced defect formation in WBG materials
<b>RG 3.2</b>	Continue developing silicon radiation damage models based on measured point and cluster defects
<b>RG 3.3</b>	Provide measurements and detector radiation damage models for radiation levels faced in HL-LHC operation
<b>RG 3.4</b>	Expand the measurements and models of silicon and WBG sensors properties in the fluence range $10^{16}$ to $1 \cdot 10^{18}$ n <sub>eq</sub> /cm <sup>2</sup>

# WP3 task, milestones, deliverables **DRD3**

WP	Task	MS or D	Description	2024	2025	2026	2027-2029	> 2030
2	2.2, 3.3	D2.4	Production of LGAD with radiation resistance up to $1 \cdot 10^{16}$ n <sub>eq</sub> /cm <sup>2</sup>				x	
3	3.3.	MS3.7	Fabrication and testing of different defect engineered Si sensors (enrichment with O, C and/or P) mimicking the gain layer in LGADs	x				
3	2.2, 3.3.	MS3.8	Understanding the effect of co-doping with O, C and/or P on the radiation hardness of gain layers in LGADs and develop defect engineered strategies for improving the radiation hardness (pin diodes 2026) and then segmented detectors (2029).			x	x	

# WP3 task, milestones, deliverables **DRD3**

WP	Task	MS or D	Description	2024	2025	2026	2027-2029	> 2030
3	3.3	D3.4	Report on microscopic and macroscopic investigations in irradiated defect engineered gain layers for Si based LGADs			x		
3	3.3	D3.5	Radiation damage studies on various silicon sensors up to $1 \cdot 10^{17}$ $n_{eq}/cm^2$ (2025) and up to $1 \cdot 10^{18}$ $n_{eq}/cm^2$ (2029)		x		x	
3	3.1	MS3.4	Understanding timing performance and validate simulation models of SiC detectors, before irradiation (2024) and at $1 \cdot 10^{15}$ $n_{eq}/cm^2$ (2030).			x		x
3	2.2, 3.1	MS3.5	SiC-LGAD (gain layer) proof of principle, simulation and first fabrication of devices with small areas ( $< 1$ $cm^2$ in 2026) and in large areas ( $5$ $cm^2$ after 2030).			x		x
3	3.1	MS3.6	Assess GaN devices as high-rate, high timing precision devices			x		

- 3<sup>rd</sup> WG3 convenor still missing
- Identify common DRD3 projects
- WG3 Organisation:
  - No subgroups for the time-being
  - Do we need liaison persons for:
    - Simulation (WG4)?
    - WBG (WG6)?
    - LGAD (WG2)?
    - Irradiations?
  - Regular meetings in between the DRD3 workshops

### **Important e-mails:**

- Convenors: [drd3-wg3-conveners@cern.ch](mailto:drd3-wg3-conveners@cern.ch)
- E-group: [drd3-wg3-radiation](mailto:drd3-wg3-radiation)